

Schottky Barrier Diode

F1AJ4

Features

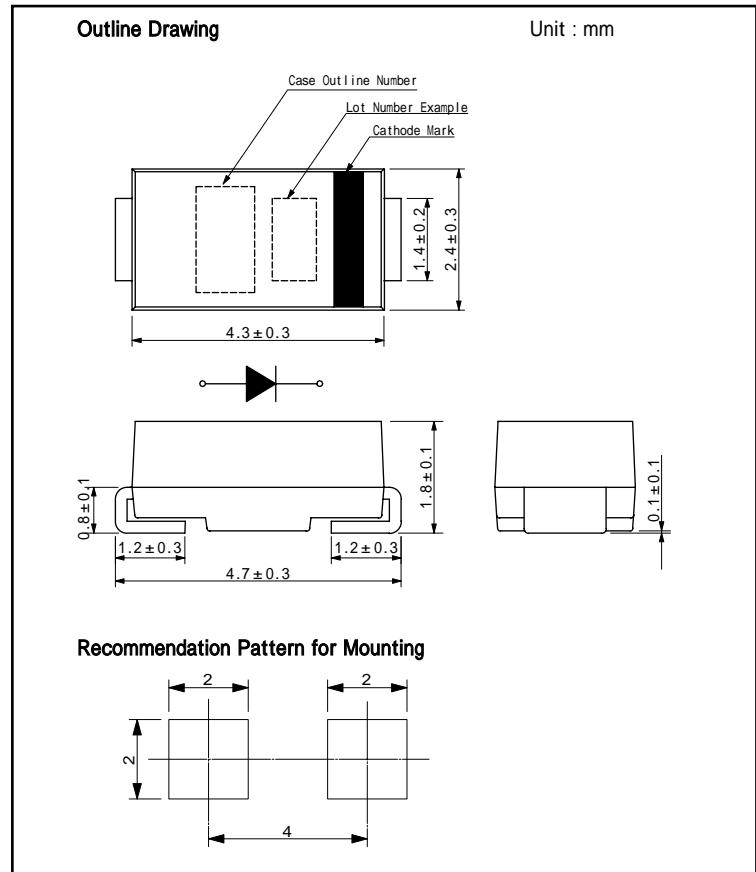
- Small and thin package
- Various kinds
- Taping capable of high density mounting

Applications

- HIC
- High-frequency rectification
- Switching regulations
- Mounting for both sides printed circuit board
- Preventing power supply from counter-flowing.
- Avoiding reverse current wrong setting of a battery.

Structures

- Resin molded, and Silicon Schottky Barrier Diode.
- Marking symbol : [AJ4]
- Weight : 0.07g
- Terminal plating : Sn
- Conforms to RoHS regulations

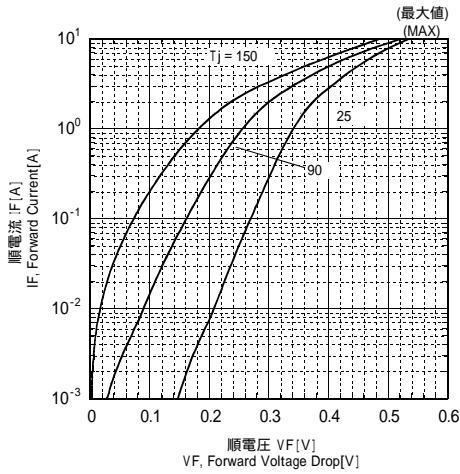
**Absolute Maximum Ratings (Ta=25)**

Items	Symbol	Conditions	Ratings	Unit
Repetitive Peak Reverse Voltage	V_{RM}		40	V
Non-Repetitive Peak Reverse Voltage	V_{RSM}		45	V
Average Rectified Forward Current	I_O	Ta=25 , DC	3	A
Peak Forward Surge Current	I_{FSM}	Tj=25 , 50Hz, Single-phase, Half sin wave, Non-Repetitive	55	A
Operating Junction Temperature	T_j		-40 ~ +150	
Storage Temperature	T_{stg}		-40 ~ +150	

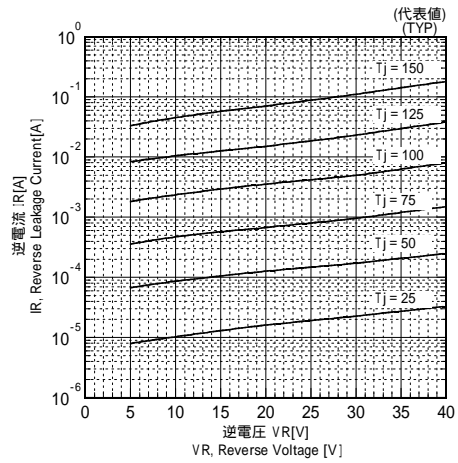
Electrical Characteristics (Tj=25)

Items	Symbol	Conditions	TYP.	MAX.	Unit
Forward Voltage Drop	V_F	$I_F=3A$	0.40	0.44	V
Reverse Leakage Current	I_R	$V_R=40V$	-	1	mA
Junction Capacitance	C_j	$V_R=10V$	160	-	pF
Terminal resistance (Junction to ambient)	$R_{th(j-a)}$	Glass Epoxy mounted. (PC board size : 20mm × 20mm , Cu land size : 4mm × 4mm)	145	-	/W

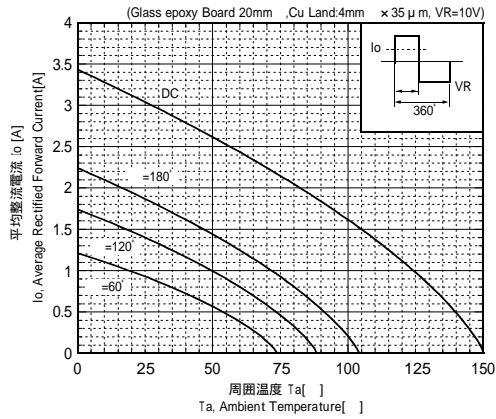
Characteristics Diagrams



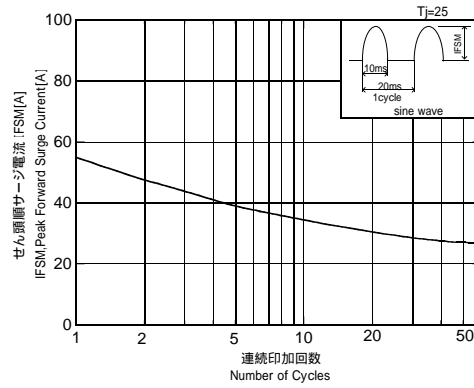
FORWARD CHARACTERISTICS



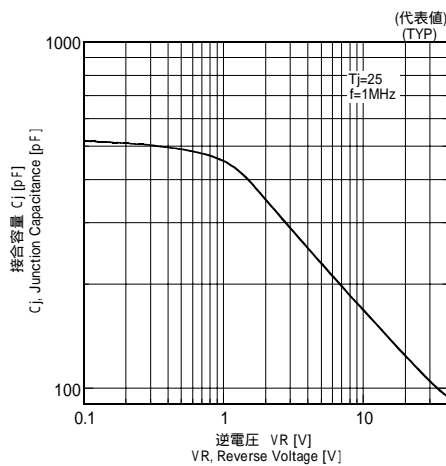
REVERSE CHARACTERISTICS



AVERAGE RECTIFIED FORWARD CURRENT



MAXIMUM FORWARD SURGE CURRENT CAPABILITY



TYPICAL JUNCTION CAPACITANCE